

BT151X series

Thyristors

Rev. 5 — 1 November 2011

Product data sheet

1. Product profile

1.1 General description

Passivated thyristors in a SOT186A full pack plastic package.

1.2 Features and benefits

- High thermal cycling performance
- High bidirectional blocking voltage capability
- Isolated mounting base.

1.3 Applications

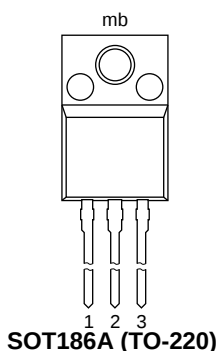
- Motor control
- Industrial and domestic lighting, heating and static switching.

1.4 Quick reference data

- $V_{\text{DRM}}, V_{\text{RRM}} \leq 800 \text{ V}$ (BT151X-800)
- $V_{\text{DRM}}, V_{\text{RRM}} \leq 650 \text{ V}$ (BT151X-650)
- $V_{\text{DRM}}, V_{\text{RRM}} \leq 500 \text{ V}$ (BT151X-500)
- $I_{\text{T(RMS)}} \leq 12 \text{ A}$
- $I_{\text{T(AV)}} \leq 7.5 \text{ A}$
- $I_{\text{TSM}} \leq 120 \text{ A}$.

2. Pinning information

Table 1. Discrete pinning

Pin	Description	Simplified outline	Symbol
1	cathode (K)		
2	anode (A)		
3	gate (G)		
mb	mounting base; isolated		

3. Ordering information

Table 2. Ordering information

Type number	Package		
	Name	Description	Version
BT151X-500	-	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3 lead TO-220 'full pack'	SOT186A
BT151X-650			
BT151X-800			

4. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM} , V_{RRM}	repetitive peak off-state voltage				
	BT151X-500	[1]	-	500	V
	BT151X-650	[1]	-	650	V
	BT151X-800		-	800	V
$I_{T(AV)}$	average on-state current	half sinewave; $T_{hs} \leq 69^\circ\text{C}$; Figure 1	-	7.5	A
$I_{T(RMS)}$	RMS on-state current	all conduction angles; Figure 4 and Figure 5	-	12	A
I_{TSM}	non-repetitive peak on-state current	half sinewave; $T_j = 25^\circ\text{C}$ prior to surge; Figure 2 and Figure 3			
		$t = 10\text{ ms}$	-	120	A
		$t = 8.3\text{ ms}$	-	132	A
I^2t	I^2t for fusing	$t = 10\text{ ms}$	-	72	A^2s
di_T/dt	repetitive rate of rise of on-state current after triggering	$I_{TM} = 20\text{ A}$; $I_G = 50\text{ mA}$; $di_G/dt\ 50\text{ mA}/\mu\text{s}$	-	50	$\text{A}/\mu\text{s}$
I_{GM}	peak gate current		-	2	A
V_{RGM}	peak reverse gate voltage		-	5	V
P_{GM}	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
T_{stg}	storage temperature		-40	+150	$^\circ\text{C}$
T_j	junction temperature		-	125	$^\circ\text{C}$

- [1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/ μs .

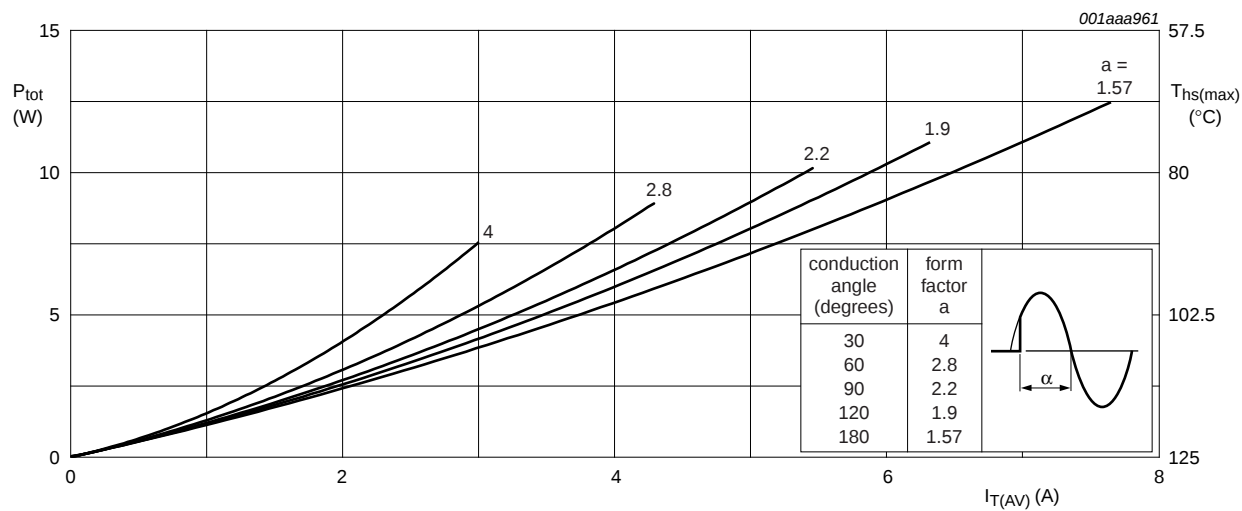


Fig 1. Total power dissipation as a function of average on-state current; maximum values

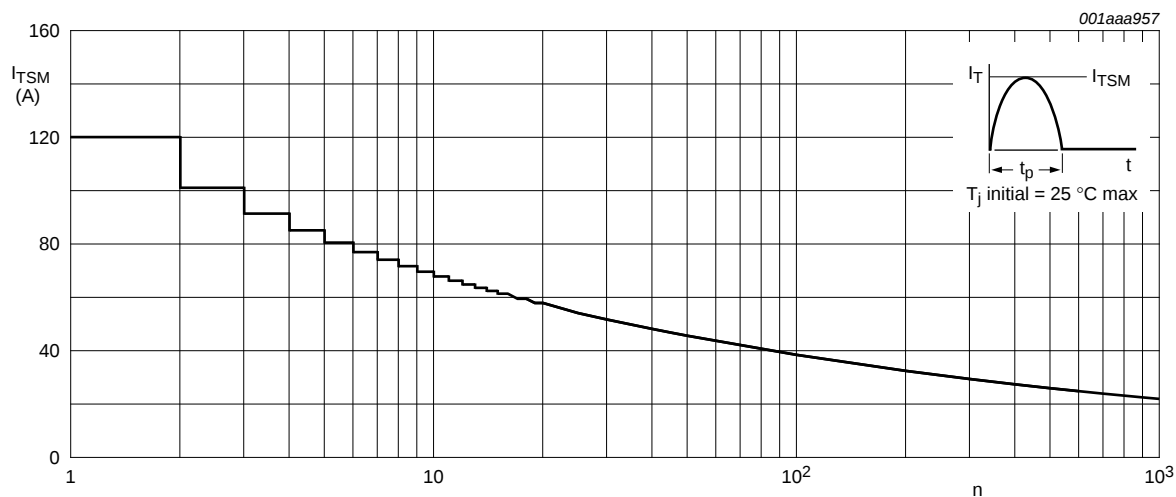
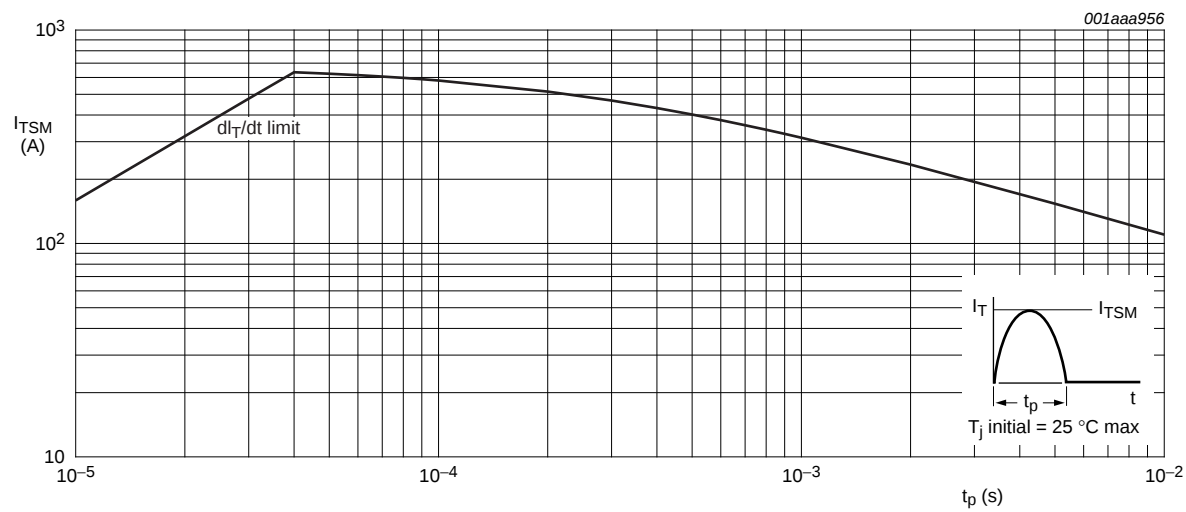
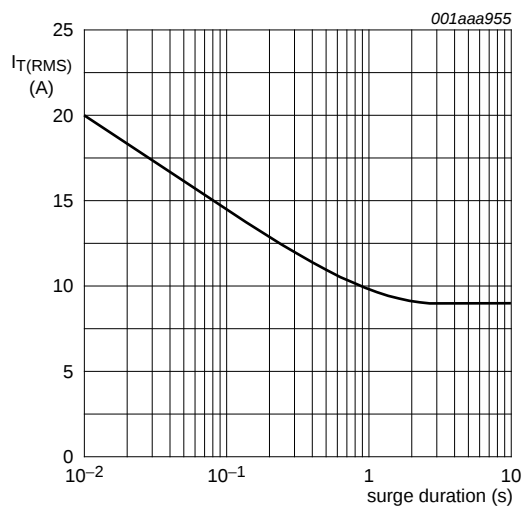


Fig 2. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values



$t_p \leq 10 \text{ ms.}$

Fig 3. Non-repetitive peak on-state current as a function of pulse width; maximum values



$f = 50 \text{ Hz; } T_{hs} \leq 87^\circ\text{C.}$

Fig 4. RMS on-state current as a function of surge duration; maximum values

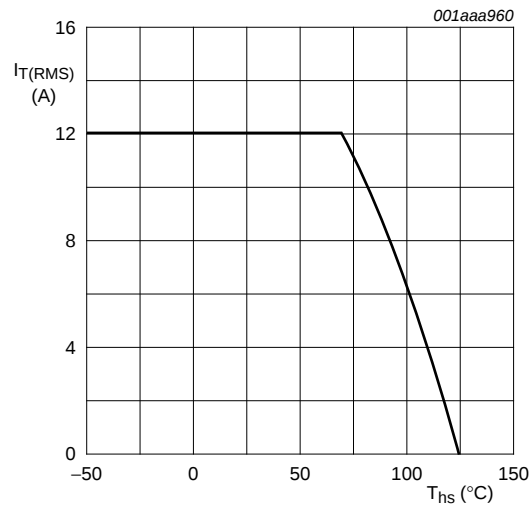
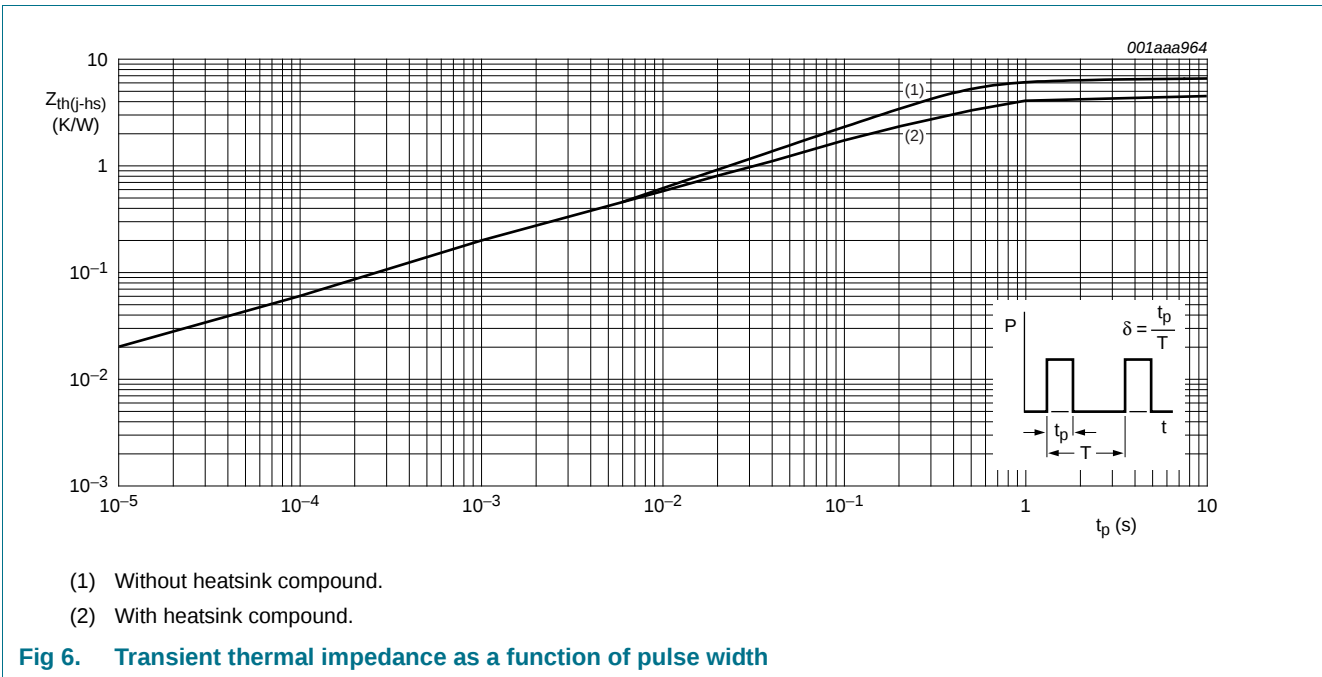


Fig 5. RMS on-state current as a function of heatsink temperature; maximum values

5. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Max	Unit
$R_{th(j-hs)}$	thermal resistance from junction to heatsink	Figure 6 with heatsink compound	-	4.5	K/W
		without heatsink compound	-	6.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	55	-	K/W



6. Isolation characteristics

Table 5. Isolation limiting values and characteristics

$T_{hs} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified

Symbol	Parameter	Conditions	Typ	Max	Unit
V_{isol}	RMS isolation voltage from all three terminals to external heatsink	$f = 50$ to 60 Hz ; sinusoidal waveform; R.H. $\leq 65\%$; clean and dust free	-	2500	V
C_{isol}	capacitance from pin 2 to external heatsink	$f = 1\text{ MHz}$	10	-	pF

7. Characteristics

Table 6. Characteristics

$T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise stated

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
I_{GT}	gate trigger current	$V_D = 12\text{ V}$; $I_T = 0.1\text{ A}$; Figure 8	-	2	15	mA
I_L	latching current	$V_D = 12\text{ V}$; $I_{GT} = 0.1\text{ A}$; Figure 10	-	10	40	mA
I_H	holding current	$V_D = 12\text{ V}$; $I_{GT} = 0.1\text{ A}$; Figure 11	-	7	20	mA
V_T	on-state voltage	$I_T = 23\text{ A}$; Figure 9	-	1.4	1.75	V
V_{GT}	gate trigger voltage	$V_D = 12\text{ V}$; $I_T = 0.1\text{ A}$; Figure 7	-	0.6	1.5	V
		$V_D = V_{DRM(max)}$; $I_T = 0.1\text{ A}$; $T_j = 125\text{ }^{\circ}\text{C}$	0.25	0.4	-	V
I_D, I_R	off-state leakage current	$V_D = V_{DRM(max)}$; $V_R = V_{RRM(max)}$; $T_j = 125\text{ }^{\circ}\text{C}$	-	0.1	0.5	mA
Dynamic characteristics						
dV_D/dt	critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}$; $T_j = 125\text{ }^{\circ}\text{C}$; exponential waveform; Figure 12				
		gate open circuit	50	130	-	V/ μs
		$R_{GK} = 100\text{ }\Omega$	200	1000	-	V/ μs
t_{gt}	gate controlled turn-on time	$I_{TM} = 40\text{ A}$; $V_D = V_{DRM(max)}$; $I_G = 0.1\text{ A}$; $dI_G/dt = 5\text{ A}/\mu\text{s}$	-	2	-	μs
t_q	circuit commuted turn-on time	$V_D = 67\% V_{DRM(max)}$; $T_j = 125\text{ }^{\circ}\text{C}$; $I_{TM} = 20\text{ A}$; $V_R = 25\text{ V}$; $dI_{TM}/dt = 30\text{ A}/\mu\text{s}$; $dV_D/dt = 50\text{ V}/\mu\text{s}$; $R_{GK} = 100\text{ }\Omega$	-	70	-	μs

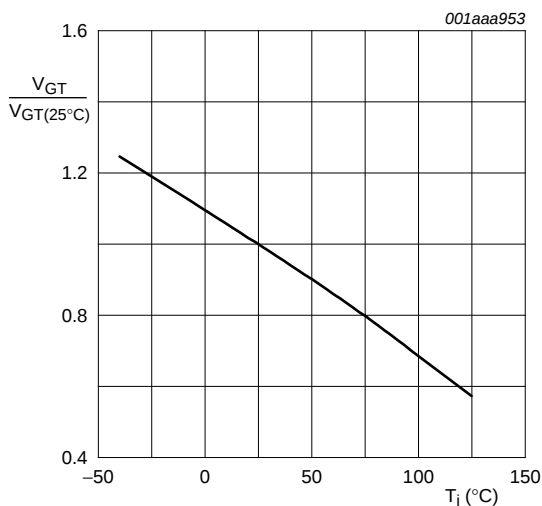


Fig 7. Normalized gate trigger voltage as a function of junction temperature

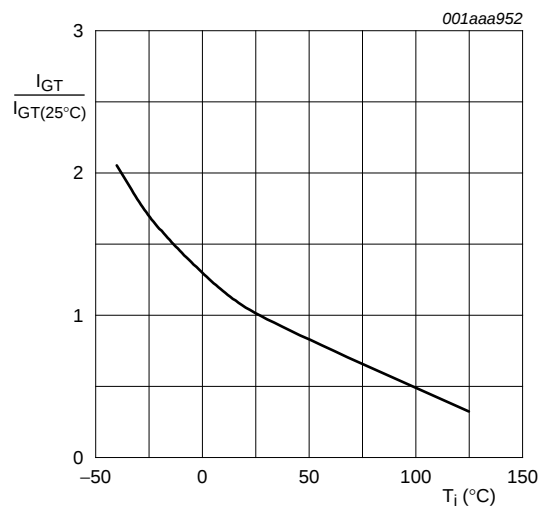
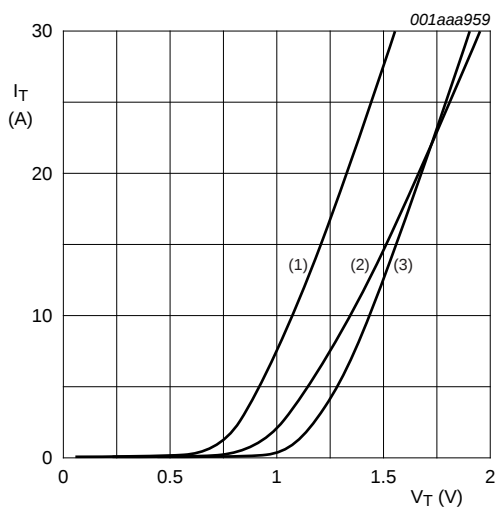


Fig 8. Normalized gate trigger current as a function of junction temperature



$V_O = 1.06\text{ V}$.
 $R_S = 0.0304\text{ }\Omega$.
(1) $T_J = 125\text{ }^\circ\text{C}$; typical values.
(2) $T_J = 125\text{ }^\circ\text{C}$; maximum values.
(3) $T_J = 25\text{ }^\circ\text{C}$; maximum values.

Fig 9. On-state current characteristics

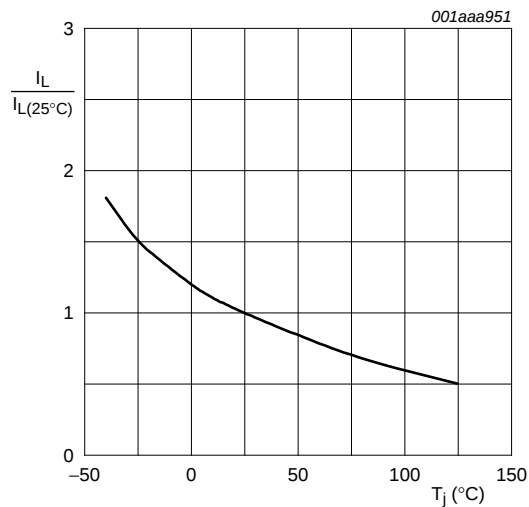


Fig 10. Normalized latching current as a function of junction temperature

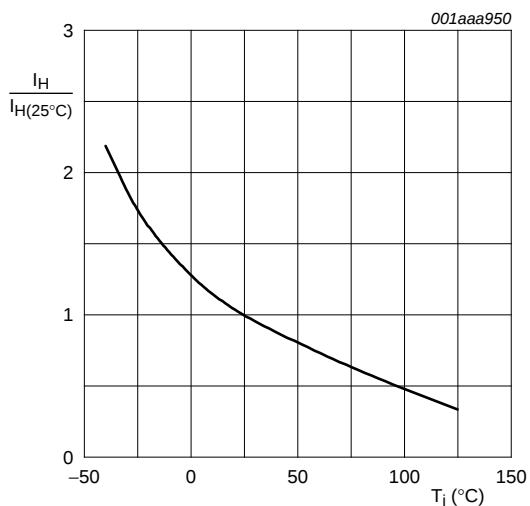
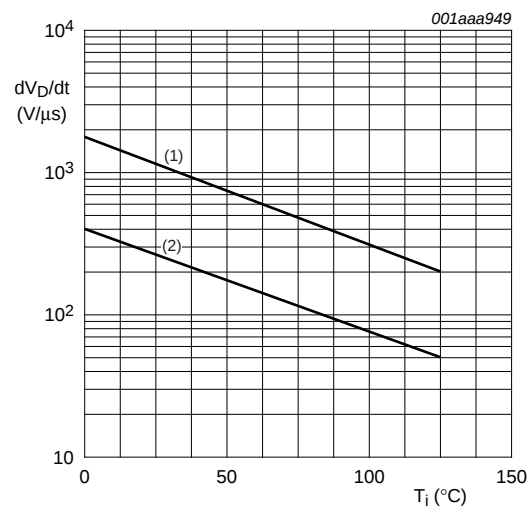


Fig 11. Normalized holding current as a function of junction temperature



(1) $R_{GK} = 100\text{ }\Omega$.
(2) Gate open circuit.

Fig 12. Critical rate of rise of off-state voltage as a function of junction temperature; minimum values

8. Package information

Epoxy meets requirements of UL94 V-0 at 1/8 inch.

9. Package outline

Plastic single-ended package; isolated heatsink mounted;
1 mounting hole; 3-lead TO-220 'full pack'

SOT186A

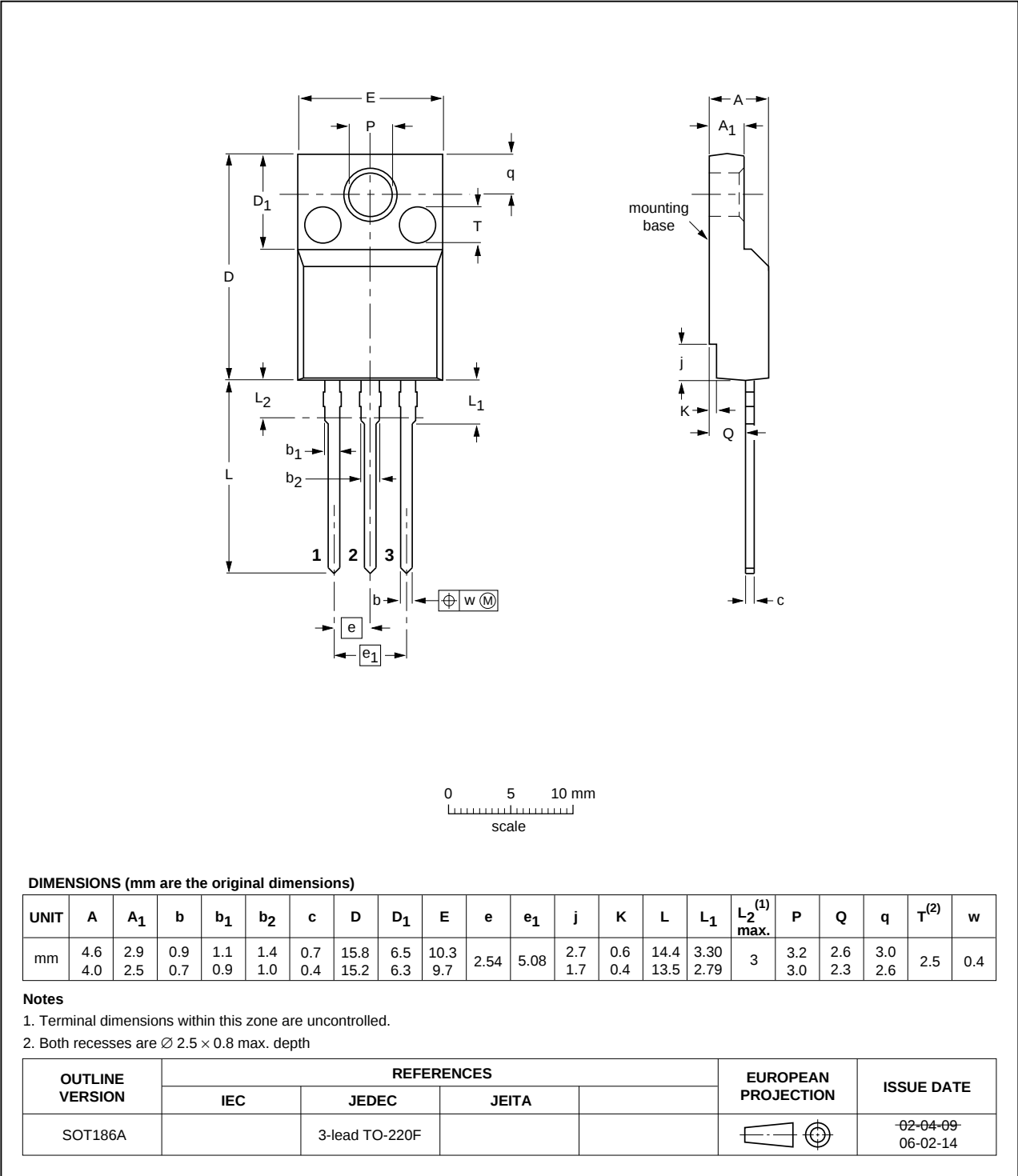


Fig 13. Package outline SOT186A (TO-220)

10. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BT151X_SER v.5	20111101	Product data sheet		BT151X_SERIES v.4
Modifications:	- The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. - Legal texts have been adapted to the new company name where appropriate.			
BT151X_SERIES v.4	20040609	Product data sheet		BT151X_SERIES v.3
BT151X_SERIES v.3	20030901	Product specification		BT151X_SERIES v.2
BT151X_SERIES v.2	19990601	Product specification		BT151X_SERIES v.1
BT151X_SERIES v.1	19970901	Product specification		-

11. Legal information

11.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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